

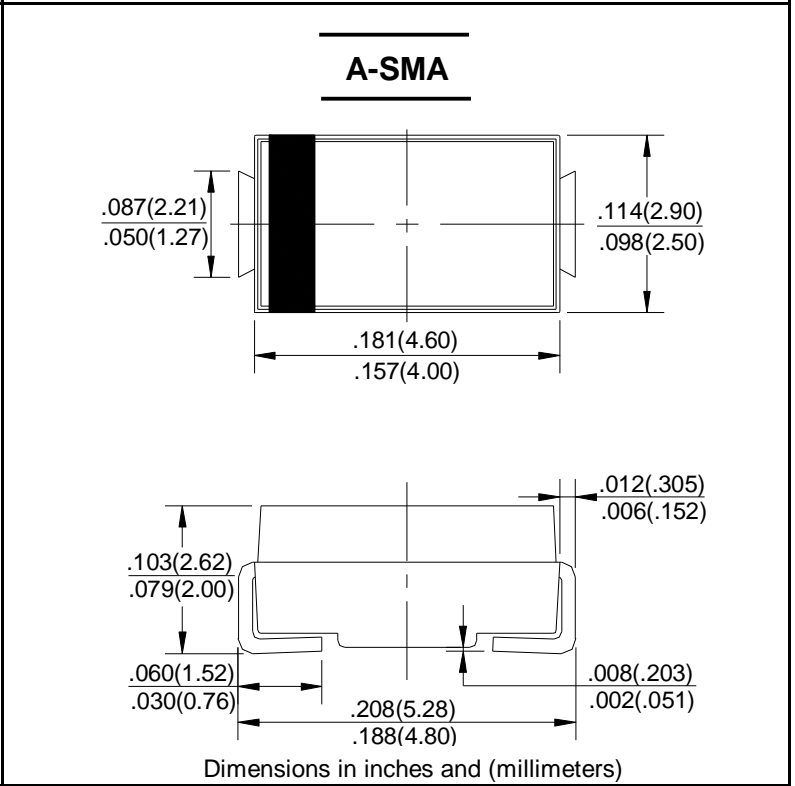
<b>SURFACE MOUNT PLASTIC SILICON RECTIFIERS</b>	<b>REVERSE VOLTAGE - 50 to 1000Volts</b> <b>FORWARD CURRENT - 1.0 Ampere</b>
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**FEATURES**

- Diffused junction
- For surface mounted applications
- Low reverse leakage current
- Low forward voltage drop
- High current capability
- Plastic material has UL flammability classification 94V-0

**MECHANICAL DATA**

- Case: Molded Plastic
- Polarity: Indicated by cathode band
- Weight: 0.002 ounces, 0.053 grams
- Mounting position: Any



**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

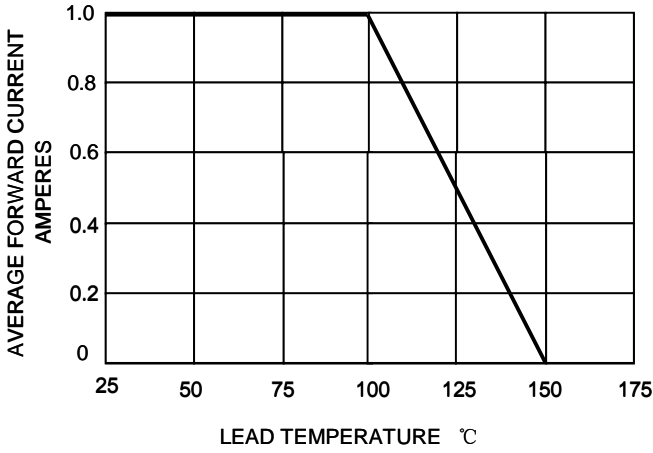
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	M1A	M2A	M3A	M4A	M5A	M6A	M7A	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @TL=100 °C	I(AV)	1.0							A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed On Rated Load (JEDEC Method)	IFSM	30							A
Maximum Forward Voltage at 1.0A DC	VF	1.1							V
Maximum DC Reverse Current @TJ=25°C at Rated DC Blocking Voltage @TJ=100°C	IR	5.0 100							µA
Typical Junction Capacitance (Note1)	CJ	10							pF
Typical Thermal Resistance (Note2)	RθJC	30							°C/W
Operating Temperature Range	TJ	-55 to +150							°C
Storage Temperature Range	TSTG	-55 to +150							°C

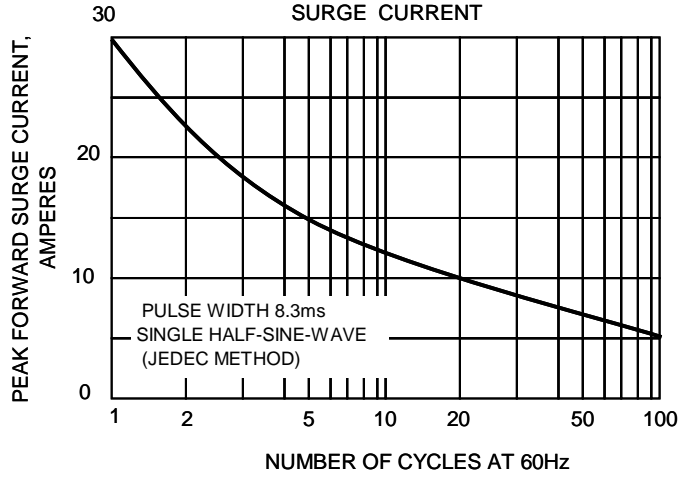
NOTES: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2. Thermal resistance junction to case.

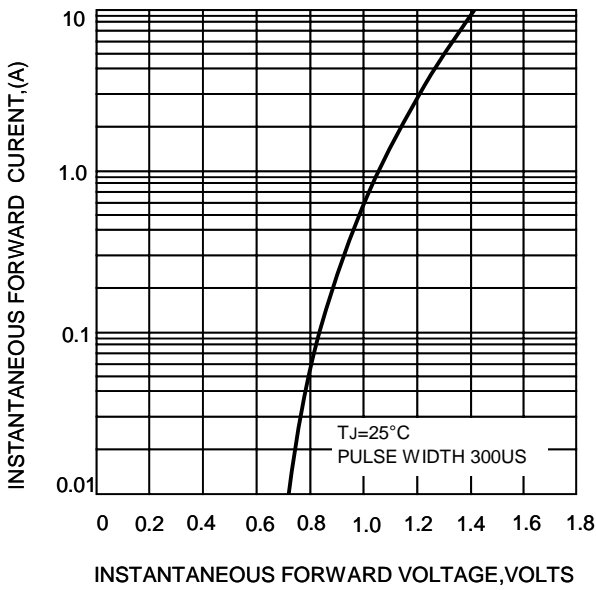
**FIG. 1 - FORWARD CURRENT DERATING CURVE**



**FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT**



**FIG.3-TYPICAL FORWARD CHARACTERISTICS**



**FIG.4-TYPICAL REVERSE CHARACTERISTICS**

